

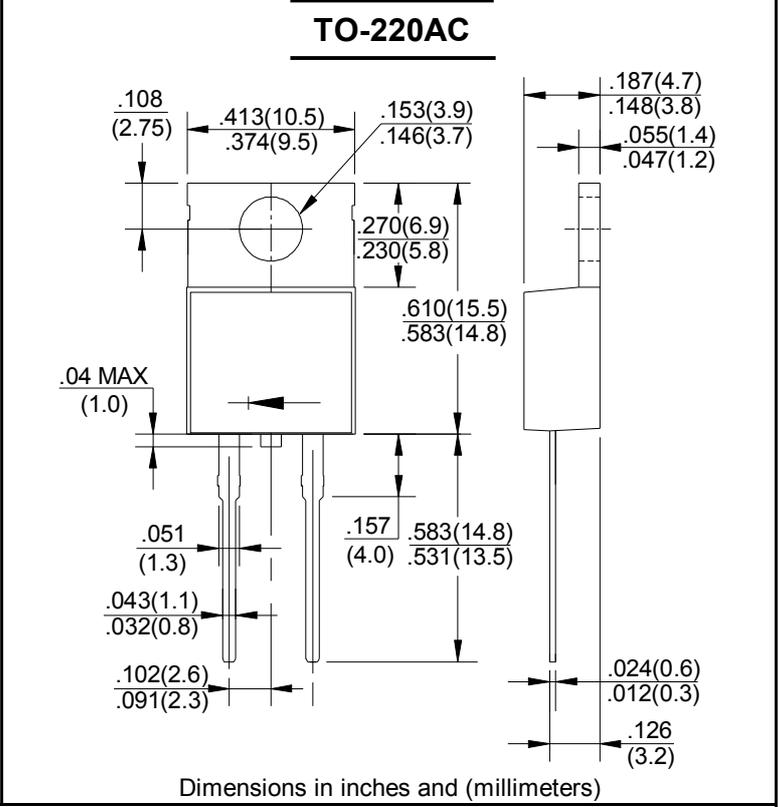
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| SCHOTTKY BARRIER RECTIFIERS | REVERSE VOLTAGE - 30 to 100Volts FORWARD CURRENT - 10.0 Amperes |
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FEATURES

- Metal of silicon rectifier , majority carrier conduction
- Guard ring for transient protection
- Low power loss,high efficiency
- High current capability,low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage,high frequency inverters,free wheeling,and polarity protection applications

MECHANICAL DATA

- Case: TO-220AC molded plastic
- Polarity: As marked on the body
- Weight: 0.08ounces,2.24 grams
- Mounting position :Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave ,60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

| CHARACTERISTICS | SYMBOL | MBR1030 | MBR1040 | MBR1050 | MBR1060 | MBR1080 | MBR10100 | UNIT |
|--|-------------------|-------------|---------|---------|---------|---------|----------|------|
| Maximum Recurrent Peak Reverse Voltage | V _{RRM} | 30 | 40 | 50 | 60 | 80 | 100 | V |
| Maximum RMS Voltage | V _{RMS} | 21 | 28 | 35 | 42 | 56 | 70 | V |
| Maximum DC Blocking Voltage | V _{DC} | 30 | 40 | 50 | 60 | 80 | 100 | V |
| Maximum Average Forward Rectified Current (See Fig.1) | I _(AV) | 10.0 | | | | | | A |
| Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method) | I _{FSM} | 150 | | | | | | A |
| Peak Forward Voltage (Note1) IF=10A @T _J =25°C IF=10A @T _J =125°C IF=20A @T _J =25°C IF=20A @T _J =125°C | V _F | 0.70 | 0.70 | 0.80 | 0.70 | 0.85 | 0.71 | V |
| Maximum DC Reverse Current at Rated DC Bolcking Voltage | I _R | 0.1 | 15 | 0.1 | 10 | 0.1 | 6.0 | mA |
| Typical Junction Capacitance (Note2) | C _J | 400 | | | | 1100 | | pF |
| Typical Thermal Resistance (Note3) | R _{θJC} | 2.5 | | | | 2.0 | | °C/W |
| Operating Temperature Range | T _J | -55 to +150 | | | | | | °C |
| Storage Temperature Range | T _{STG} | -55 to +175 | | | | | | °C |

NOTES:1.300us pulse width,2% duty cycle.
 2.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
 3.Thermal resistance junction to case.

RATING AND CHARACTERISTIC CURVES
MBR1030 thru MBR10100



FIG. 1 - FORWARD CURRENT DERATING CURVE

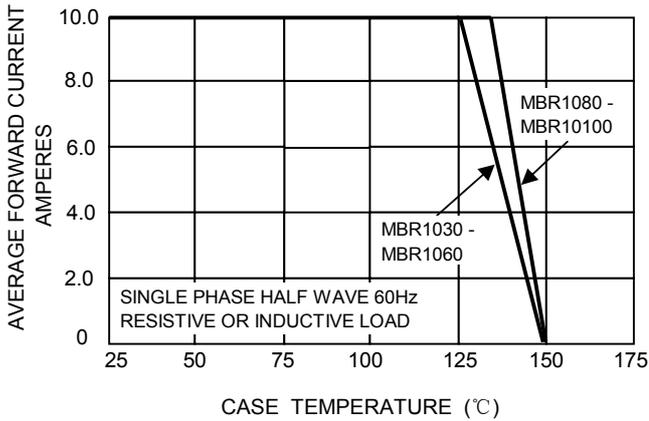


FIG. 2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

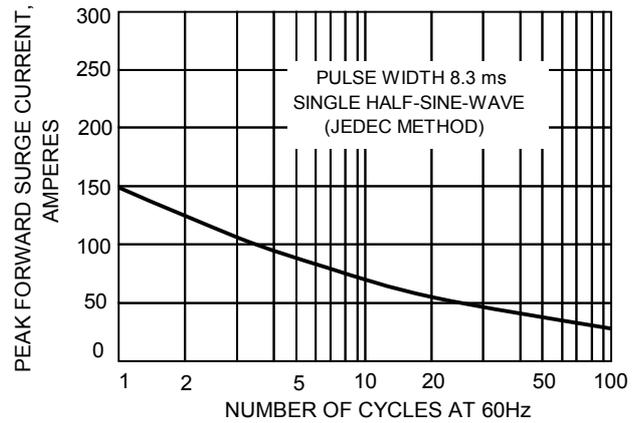


FIG.3-TYPICAL REVER CHARACTERISTICS

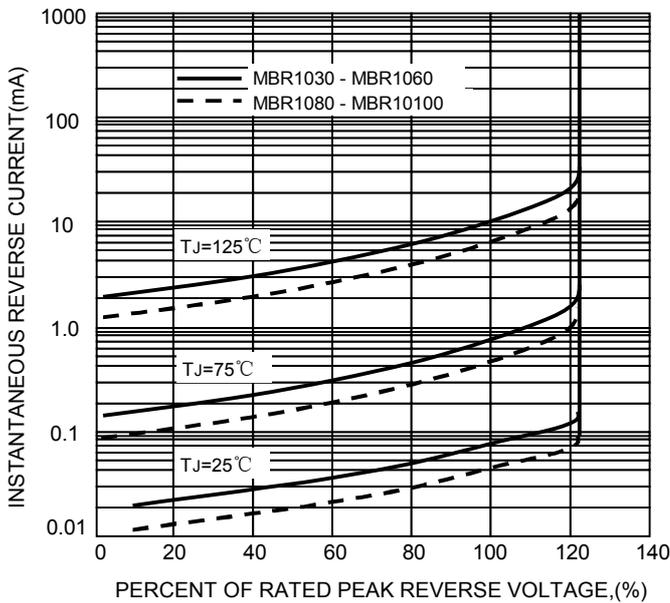


FIG.4-TYPICAL FORWARD CHARACTERISTICS

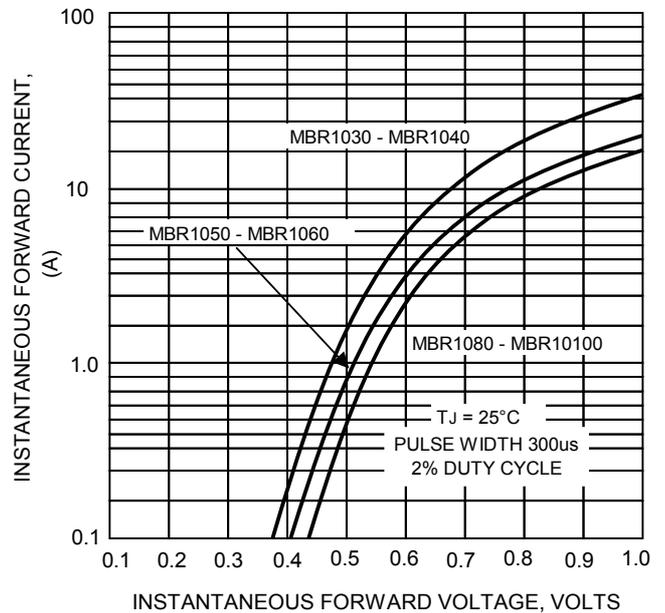


FIG.5 - TYPICAL JUNCTION CAPACITANCE

